

**SOT-323 DIGITAL TRANSISTOR
TRANSISTORS(NPN)**

FEATURES

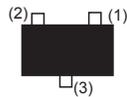
- * Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors.(see equivalent circuit).
- * The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- * Only the on/off conditions need to be set for operation marking device design easy.

MECHANICAL DATA

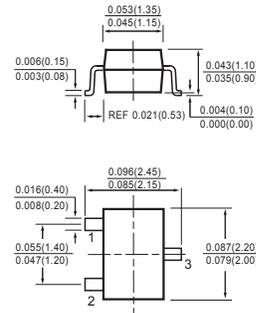
- * Case: Molded plastic
- * Epoxy: UL 94V-O rate flame retardant
- * Lead: MIL-STD-202E method 208C guaranteed
- * Mounting position: Any
- * Weight: 0.006 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.



- (1) Base
- (2) Emitter
- (3) Collector



Dimensions in inches and (millimeters)

MAXIMUM RATINGS (@ TA = 25°C unless otherwise noted)

| RATINGS | SYMBOL | VALUE | UNITS |
|-----------------------------|---------------|---------|-------|
| Collector-base voltage | $V_{(BR)CBO}$ | 50 | V |
| Collector-emitter voltage | $V_{(BR)CEO}$ | 50 | V |
| Emitter-base voltage | $V_{(BR)EBO}$ | 5 | V |
| Collector current | I_C | 100 | mA |
| Collector power dissipation | P_C | 200 | mW |
| Junction temperature | T_J | 150 | °C |
| Storage temperature | T_{stg} | -55~150 | °C |

ELECTRICAL CHARACTERISTICS (@ TA = 25°C unless otherwise noted)

| CHARACTERISTICS | SYMBOL | MIN. | TYP. | MAX. | UNITS |
|--|---------------|------|------|------|------------|
| Collector-base breakdown voltage ($I_C = 50\mu A$) | $V_{(BR)CBO}$ | 50 | - | - | V |
| Collector-emitter breakdown voltage ($I_C = 1mA$) | $V_{(BR)CEO}$ | 50 | - | - | V |
| Emitter-base breakdown voltage ($I_E = 50\mu A$) | $V_{(BR)EBO}$ | 5 | - | - | V |
| Collector cut-off current ($V_{CB} = 50V$) | I_{CBO} | - | - | 0.5 | μA |
| Emitter cut-off current ($V_{EB} = 4V$) | I_{EBO} | - | - | 0.5 | μA |
| Collector-emitter saturation voltage ($I_C = 5mA, I_B = 0.25mA$) | h_{FE} | - | - | 0.3 | V |
| DC current gain ($V_{CE} = 5V, I_C = 1mA$) | $V_{CE(sat)}$ | 100 | - | 600 | - |
| Input resistor | R_1 | 3.29 | 4.7 | 6.11 | K Ω |
| Transition frequency ($V_O = 10V, I_O = 5mA, f = 100MHz$) | f_T | - | 250 | - | MHz |

RATING AND CHARACTERISTICS CURVES (DTC143TUA)

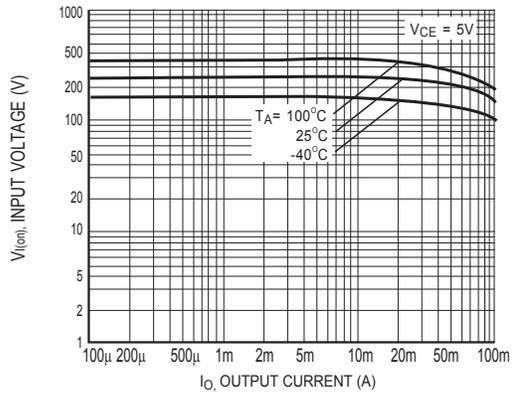


Figure1 Input voltage vs. output current (ON Characteristics)

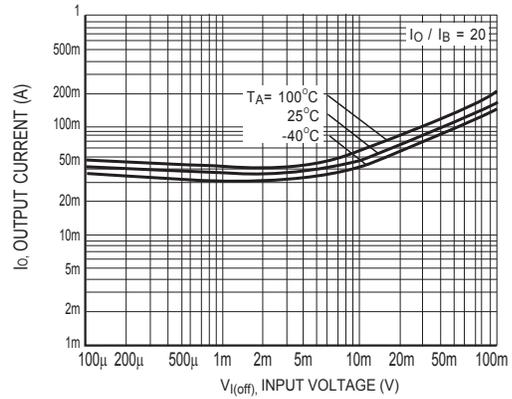


Figure2 Output current vs. input voltage (OFF Characteristics)

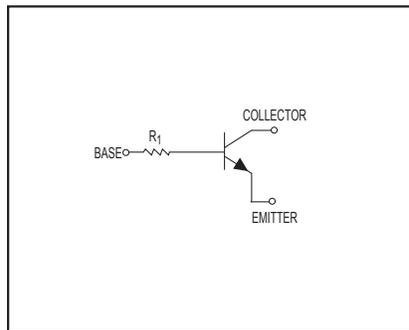


Figure3 Equivalent circuit

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